

GI31C

NPN EPITAXIAL PLANAR TRANSISTOR

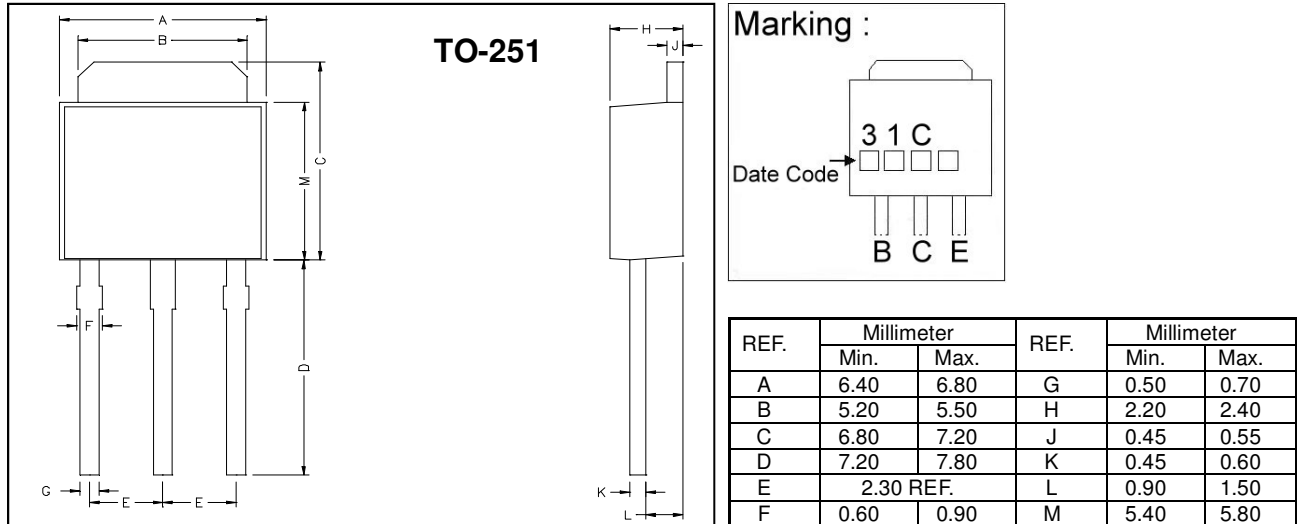
Description

The GI31C is designed for use in general purpose amplifier and switching applications.

Features

*Complementary to GI32C

Package Dimensions



Absolute Maximum Ratings (Ta = 25°C, unless otherwise specified)

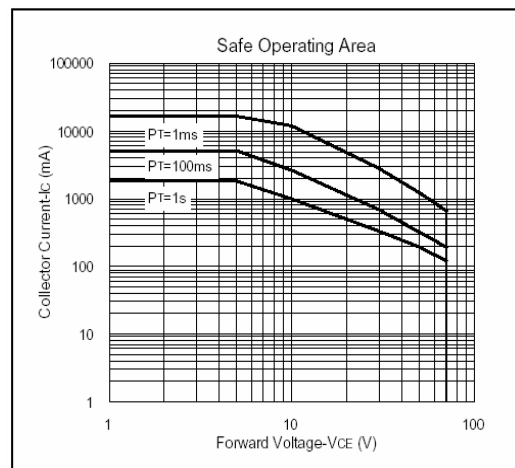
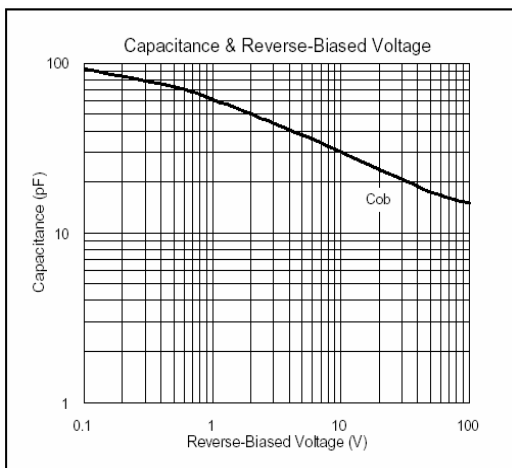
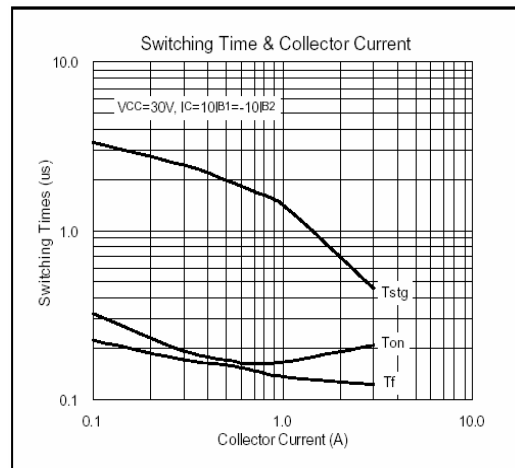
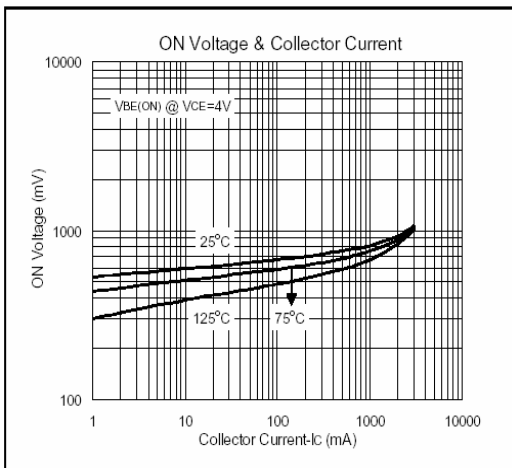
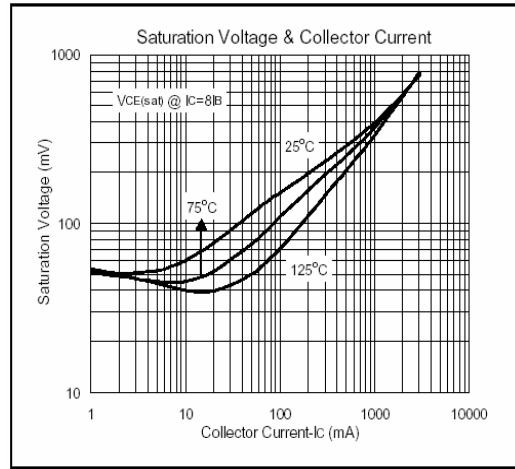
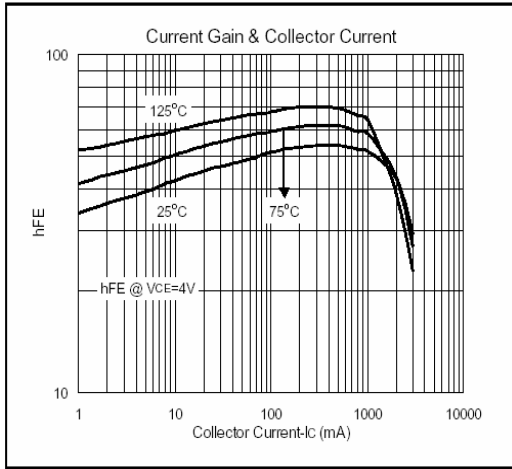
Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	V _{CBO}	100	V
Collector to Emitter Voltage	V _{CEO}	100	V
Emitter to Base Voltage	V _{EBO}	5	V
Collector Current (DC)	I _c	3	A
Collector Current (Pulse)	I _c	5	A
Junction Temperature	T _j	+150	°C
Storage Temperature	T _{STG}	-55 ~ +150	°C
Total Power Dissipation	PD	2	W
	PD(Tc=25°C)	15	W

Electrical Characteristics (Rating at Ta=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV _{CBO}	100	-	-	V	I _c =1mA, I _E =0
BV _{CEO}	100	-	-	V	I _c =30mA, I _B =0
BV _{EBO}	5	-	-	V	I _E =100uA, I _c =0
I _{CES}	-	-	20	uA	V _{CE} =100V, V _{EB} =0V
I _{CEO}	-	-	50	uA	V _{CE} =60V, I _B =0
I _{EBO}	-	-	1	mA	V _{EB} =5V, I _c =0
*V _{CE(sat)}	-	-	1.2	V	I _c =3A, I _B =375mA
*V _{BE(on)}	-	-	1.8	V	V _{CE} =4V, I _c =3A
*h _{FE1}	25	-	-		V _{CE} =4V, I _c =1A
*h _{FE2}	10	-	50		V _{CE} =4V, I _c =3A
f _T	3	-	-	MHz	V _{CE} =10V, I _c =500mA, f=1MHz

* Pulse Test: Pulse Width ≤ 380μs, Duty Cycle ≤ 2%

Characteristics Curve



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